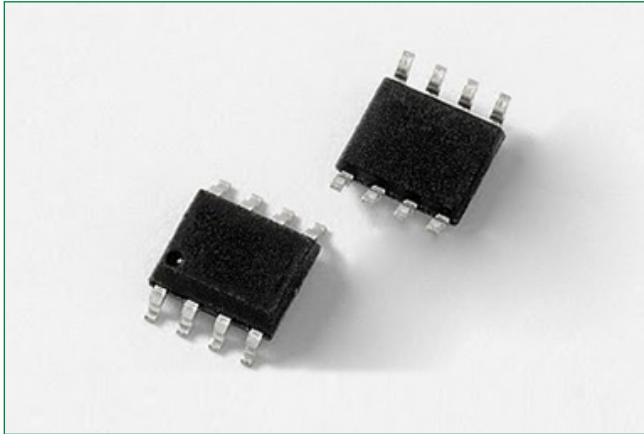


# B61089QDR, Dual port negative voltage tracking SLIC protector SOP-8

## Programmable Battery tracking protection



### Description

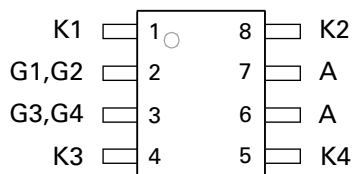
The B61089QDR is a dual channel SLIC (Subscriber Line Interface circuit) battery tracking protector. It consists of two pairs of identical protection thyristors integrated with two anti-series diodes to protect the SLIC against lightning induced surges and power fault events. It is designed specifically for dense component PC boards in modern telecom and datacom applications where space is a concern.

The gated thyristor protectors which have crowbarbing function, provide tracking battery protection down to -170V. The anti-series diode provides protection of positive surge events by diverting the surge energy to the ground.

The B61089QDR has a robust surge current capability which helps the telecom and datacom products to comply with different surge standards such as Telcordia GR-1089, ITU-T K.20, K.21 and YD/T950. For compliance with Enhanced Levels test conditions of ITU-T, TIA968-B, or GR-1089, additional series resistance in the Tip / Ring pairs may be required.

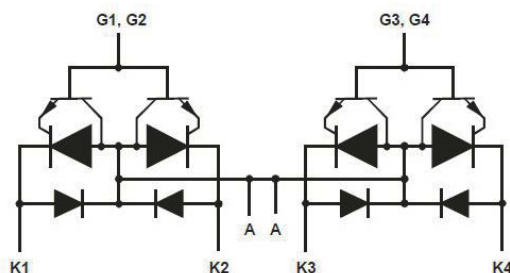
The SLIC chipset voltage reference may change as the on-hook/off-hook line condition changes. Therefore, this component is referenced to the -VBAT so that its negative protection threshold follows this changing reference voltage level. This B61089QDR utilizes a transistor gain network so that a low 5 mA current level will activate the thyristor based portion of this protector component during negative events. This also allows an easier turn on during slow rising power fault events. For all positive disturbances, the fast switching diode connected to earth reference will provide the needed protection.

### Pinout Designation



Pin #	Pin Name	Description
1, 4, 5, 8	K1, K3, K4, K2	Connect to subscriber lines (Tip/Ring)
2, 3	G1, G2, G3, G4	Connect to battery (Reference Voltage)
6, 7	A	Connect to ground (earth)

### Schematic Symbol



### Features

- Dual port negative voltage tracking programmable component
- Supports battery voltages down to -170V
- Low gate triggering current 5 mA max
- Fails in a short circuit condition when it is surged in excess of its ratings to protect all downstream equipment
- Surge capability does not degrade after multiple surge events within its ratings
- High holding current -150mA min
- Specified 2/10 limiting voltage
- Integrated diodes for positive surge protection
- MSL: Level 1 - unlimited
- RoHS compliant and lead-free

### Applicable Global Standards

- Wireless In the Local Loop (WLL)
- Voice applications which require regenerated POTS
- VoIP applications
- PBX
- FXS applications
- Digital Pair Gain systems (DPG) and Digital Loop Carrier systems (DLC)
- Small Office Home Office (SOHO)

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### Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ )

Symbol	Parameter	Test Conditions	Value	Unit
$I_{PPSM}^*$	Non-repetitive peak on-state pulse current	10/1000 $\mu\text{s}$	35	A
		5/310 $\mu\text{s}$	65	
		2/10 $\mu\text{s}$	180	
		8/20 $\mu\text{s}$	170	
$I_{TSM}/I_{FSM}^*$	Non repetitive peak on-state current, 50Hz/60Hz	0.5s	12	A
		1s	9	
		5s	7	
		30s	4	
		900s	3	
$I_{GSM}^*$	Non repetitive peak gate current, 2/10 $\mu\text{s}$ pulse, cathodes commoned		40	A
$V_{DRM}$	Repetitive peak off-state voltage, $V_{GK}=0$		-170	V
$V_{GKRM}$	Repetitive peak gate-cathode voltage, $V_{KA}=0$		-167	V
$T_A$	Operating free-air temperature range		-40 - 85	$^\circ\text{C}$
$T_{STG}$	Storage temperature range		-40 - 150	$^\circ\text{C}$
$T_J$	Junction temperature		-40 - 150	$^\circ\text{C}$
$T_L$	Maximum lead temperature for soldering during 10s		260	$^\circ\text{C}$
$R_{\theta JA}$	Junction to ambient thermal resistance	$P_{tot} = 0.8 \text{ W}, T_A = 25^\circ\text{C}, 5 \text{ cm}^2, \text{FR4 PCB}$	160	$^\circ\text{C/W}$

\* Notes :

- Initially the protector must be in thermal equilibrium with  $T_J=25^\circ\text{C}$ . The surge may be repeated after the component returns to its initial conditions.

- These non-repetitive rated currents are peak values for either polarity. The rated current values may be applied to any cathode-anode terminal pair. Additionally, all cathode-anode terminal pairs may have their rated current values applied simultaneously (in this case the anode terminal current will be four times the rated current value of an individual terminal pair).

### Electrical Characteristics

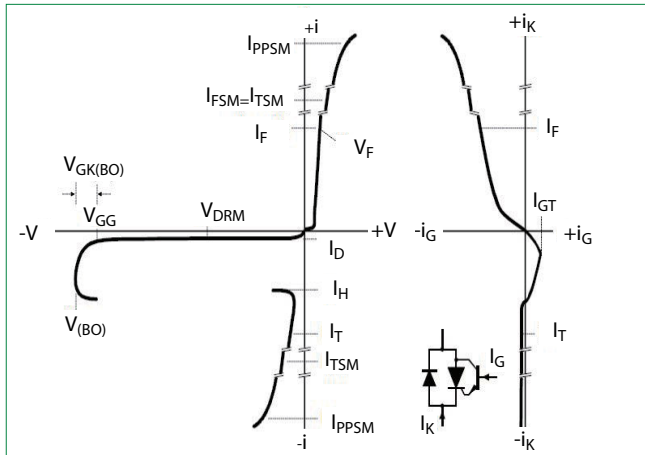
Symbol	Parameter	Test Conditions	Max	Unit
$V_F$	Forward voltage	$I_F=5\text{A}, t_w=200\mu\text{s}$	3	V
$V_{FRM}$	Impulse peak forward recovery voltage	2/10 $\mu\text{s}$ , $I_{TM}=-27\text{A}, R_s=50\Omega, di/dt=-27\text{A}/\mu\text{s}$	12	V
$I_D$	Off-state current	$V_D = V_{DRM}, V_{GK}=0, T_J=25^\circ\text{C}$	-5	$\mu\text{A}$
$V_{(BO)}$	Impulse breakover voltage	2/10 $\mu\text{s}$ , $I_{TM}=-27\text{A}, R_s=50\Omega, di/dt=-27\text{A}/\mu\text{s}, V_{GG}=-100\text{V}$	-115	V
$V_{GK(BO)}$	Gate-cathode impulse breakover voltage	2/10 $\mu\text{s}$ , $I_{TM}=-27\text{A}, R_s=50\Omega, di/dt=-27\text{A}/\mu\text{s}, V_{GG}=-100\text{V}$	20	V
$I_H$	Holding current	$I_T=-1\text{A}, di/dt=1\text{A}/\text{ms}, V_{GG}=-100\text{V}$	-150 (min)	mA
$I_{GKS}$	Gate reverse current	$V_{GG}=V_{GK}=V_{GKRM}, V_{KA}=0, T_J=25^\circ\text{C}$	-5	$\mu\text{A}$
$I_{GT}$	Gate trigger current	$I_T=-3\text{A}, t_{plg}^* \geq 20\mu\text{s}, V_{GG}=-100\text{V}, T_J=25^\circ\text{C}$	5	mA
$V_{GT}$	Gate trigger voltage	$I_T=-3\text{A}, t_{plg}^* \geq 20\mu\text{s}, V_{GG}=-100\text{V}$	2.5	V
$C_{KA}$	Cathode-anode off-state capacitance	$f=1\text{MHz}, V_d=1\text{V}, I_G=0, V_D=-3\text{V}$	100	pF
		$f=1\text{MHz}, V_d=1\text{V}, I_G=0, V_D=-48\text{V}$	50	

\* $T_{plg}$ : gate pulse time

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## Programmable Battery tracking protection

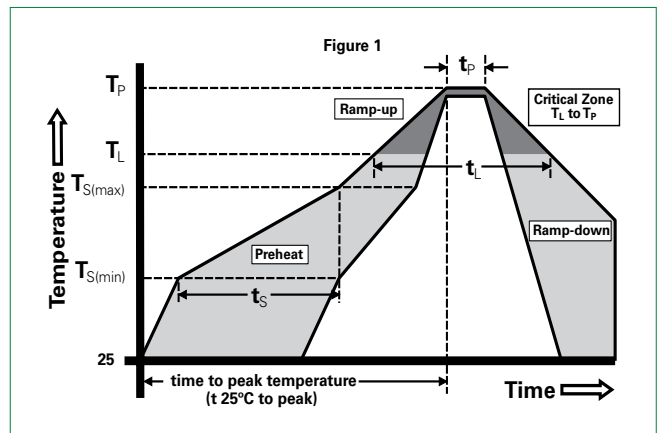
### V-I Characteristics



Parameter	Symbol
Off-state current	$I_D$
Repetitive peak off-state voltage	$V_{DRM}$
On-state Current(RMS)	$I_T$
Non-repetitive Peak On-state Current	$I_{TSM}$
Holding current	$I_H$
Breakover voltage	$V_{(BO)}$
Forward voltage	$V_F$
Gate-cathode impulse breakover voltage	$V_{GK(BO)}$
Gate trigger current	$I_{GT}$
SLIC supply voltage	$V_{GG}$

### Soldering Parameters

Reflow Condition		Pb-Free assembly
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	+150°C
	-Temperature Max ( $T_{s(max)}$ )	+200°C
	-Time (Min to Max) ( $t_s$ )	60-120 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		3°C/sec. Max.
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		3°C/sec. Max.
Reflow	-Temperature ( $T_L$ ) (Liquidus)	+217°C
	-Temperature ( $t_L$ )	60-150 secs.
Peak Temp ( $T_p$ )		+260(+0/-5)°C
Time within 5°C of actual Peak Temp ( $t_p$ )		30 secs. Max.
Ramp-down Rate		6°C/sec. Max.
Time 25°C to Peak Temp ( $T_p$ )		8 min. Max.
Do not exceed		+260°C



### Physical Specifications

<b>Lead Material</b>	Copper Alloy
<b>Terminal Finish</b>	100% Matte-Tin Plated
<b>Body Material</b>	UL Recognized compound meeting flammability rating V-0

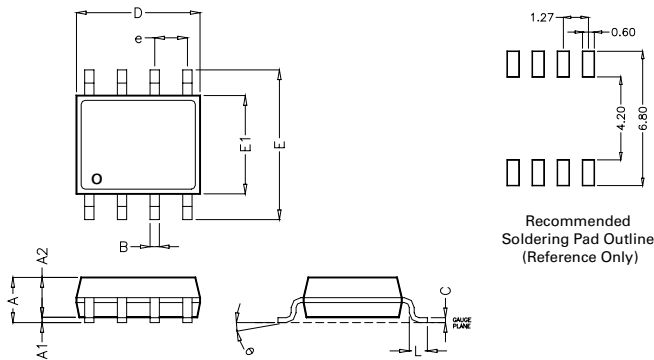
### Environmental Specifications

<b>High Temp Voltage Blocking</b>	*Rated 75V (A=75V, K=0V, G=0V) +150°C, 1008hrs. MIL-STD-750 (Method 1040) JEDEC, JESD22-A-101
<b>Temp Cycling</b>	-55°C to +150°C, 15 min. dwell, 1000cycles. MIL-STD-750 (Method 1051) EIA/JEDEC, JESD22-A104
<b>Biased Temp &amp; Humidity</b>	Rated 50V (A=50V, K=0V, G=0V) (+85°C) 85% RH, 1008 hrs. EIA/JEDEC, JESD22-A-101
<b>Resistance to Solder Heat</b>	+260°C, 10 secs. JESD22-A111
<b>Moisture Sensitivity Level</b>	*85%RH, +85°C, 168 hrs., 3 reflow cycles (+260°C Peak). JEDEC-J-STD-020, Level 1"

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Programmable Battery tracking protection

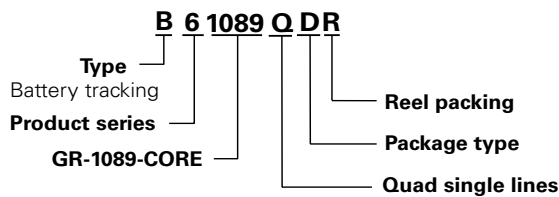
## Dimensions – MS-012 (SOP-8)



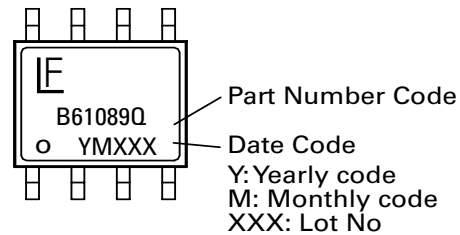
Dimension	Inches		Millimeters	
	MIN	MAX	MIN	MAX
A	0.053	0.069	1.35	1.75
A1	0.004	0.010	0.10	0.25
A2	0.043	0.065	1.25	1.65
B	0.012	0.020	0.31	0.51
C	0.007	0.010	0.17	0.25
D	0.189	0.197	4.80	5.00
E	0.228	0.244	5.80	6.20
E1	0.150	0.157	3.80	4.00
e	0.050 BSC*		1.27 BSC*	
L	0.016	0.050	0.40	1.27

\* BSC = Basic Spacing between Centers

## Part Numbering



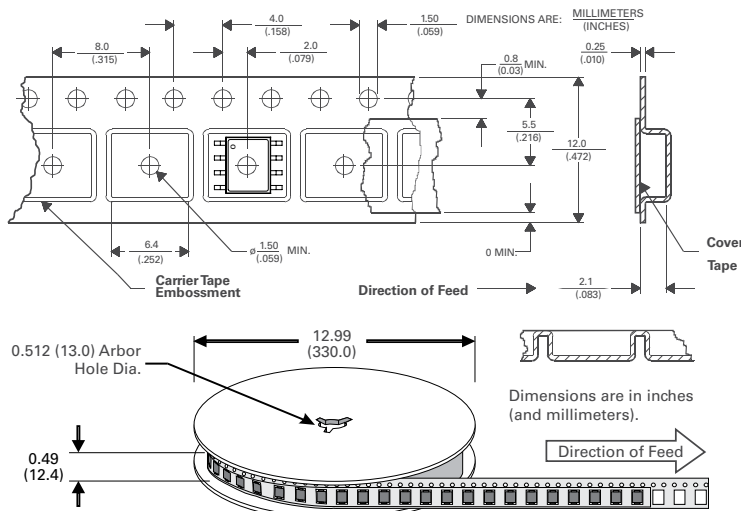
## Part Marking



## Packing Options

Package Type	Description	Quantity	Added Suffix	Industry Standard
D	MS-012 SMT 8-pin SOP-8 Tape and Reel Pack	2500	N/A	EIA-481-D

## Tape and Reel Specifications – MS-012 (SOP-8)



# B61089QDR, Dual port negative voltage tracking SLIC protector SOP-8

## Programmable Battery tracking protection

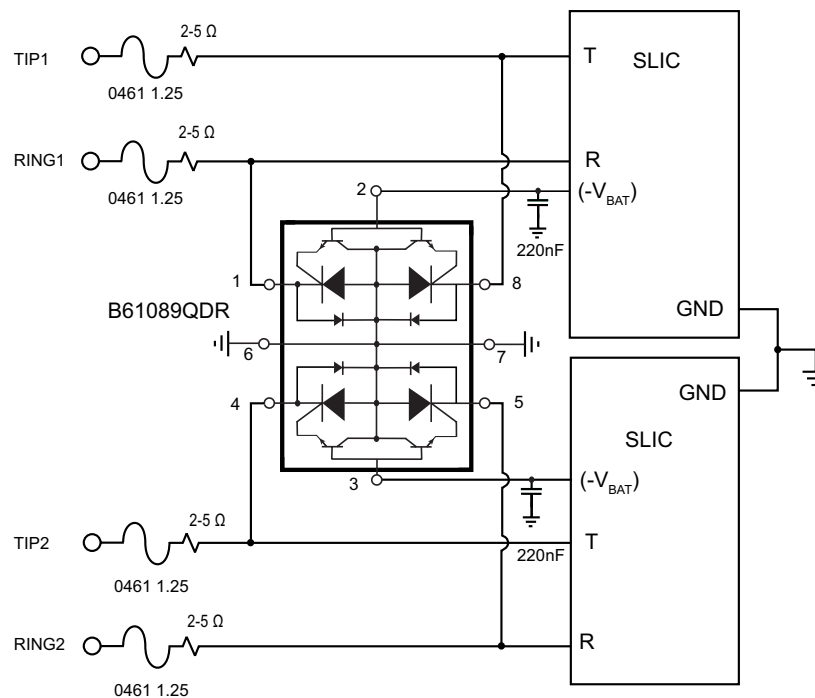
### Application Note

This B61089QDR MS-012 SMT (SOP-8) Dual port Batrax® is specifically designed to provide surge protection for SLIC (Subscriber Line Interface Circuit) cards implementing negative ringing only. This single 8-pin component provides protection for two SLIC ports (T1/R1 & T2/R2) by shunting positive and negative surges to the ground reference.

The negative surges are diverted to ground through the SCRs which are connected between the TIP/RING conductors and the ground reference. These SCRs have a transistor buffered gate that provides a low current magnitude trigger level; typically 5 mA or less. The SCRs will reset when the magnitude of the loop current drops below the component's holding current parameter  $I_H$ . The fast switching diodes will turn on for any positive surge event  $> 3V$  between tip and ground or between ring and ground.

This SCR's turn-on threshold for negative polarity events tracks the negative reference voltage ( $-V_{BAT}$ ) of the SMART SLIC component. As the line conditions change from off-hook to on-hook, the SLIC reference voltage level will also change in an effort to conserve energy. The negative tracking protection component will typically operate at a voltage of  $-1.4V$  below  $-V_{BAT}$  during negative surge conditions or power fault events.

The two gate capacitors, which act as charge reservoirs, supply the needed current to trigger the thyristor components to the on-state and should be physically located in close proximity to the B61089QDR gate (pins 2&3). During slow rising ac power fault events, the discharge current of the capacitor ( $I_c = C dv/dt$ ) easily achieves the 5 mA threshold to activate the SCR. This solution below will comply with the power fault and surge requirements of GR-1089 Intra-building Port Type and the Basic level of ITU K20/21. For GR-1089 Port Type 3 and Enhanced level of ITU K20/21, the series resistor value may need to be increased. The TeleLink fuse complies with both GR-1089 intra-building and inter-building requirements and both Basic and Enhanced levels of the ITU Recommendations.



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